

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	1040	(438/95).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/29 15:13
L11	34	10 and (@pd>"20060101")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/29 15:34
L12	1288	(438/102).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/29 15:33
L13	15	12 and (@pd>"20060101")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/29 15:34
L14	1026	((resist\$4 near5 variable) (chalcogenide near2 glass)) and electrode and (metal near3 contain\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/29 15:39
L15	884	14 and voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/29 15:39
L16	314	15 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/29 15:47
L17	3	("6813178").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/29 15:47

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L7	2	(electrode and (resist\$4 near2 variable near2 material) and (metal adj contain\$3) and (conduct\$3 near2 channel) and (condition\$3 near2 voltage)).clm.	US-PGPUB	OR	ON	2006/08/29 17:25